

## Single Bus Buffer Gate With 3-State Output

### Description

The single buffer is designed for 0.8-V to 3.6-V VCC operation.

The FLG74AUP1G126 device is a single line driver with a 3-state output. The output is disabled when the output-enable input is low.

The FLG74AUP1G126 device is available in a variety of packages, including SOT23-5, SC70.

### Features

- Inputs Accept Voltages 0.8V to 3.6 V
- Max Tpd of 4.7 ns at 3.3 V
- Low Static-Consumption, 0.5-  $\mu$  A Max  $I_{CC}$
- Low Noise Overshoot and Undershoot < 10% of  $V_{CC}$
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input ( $V_{hys}$  = 250mV Typical

3.3V)

- 3.6V I/O Tolerant to Support Mixed-Mode Signal Operation
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)

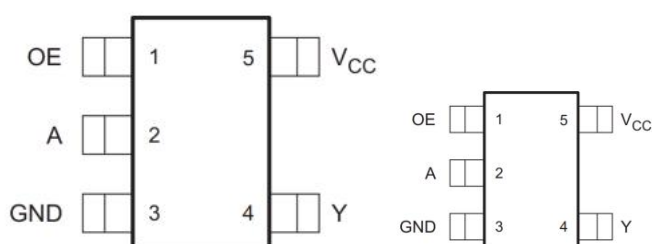
### Applications

- Audio Dock: Portable
- BluRay™ Players and Home Theaters
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid-State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Wireless Headsets, Keyboards and Mice

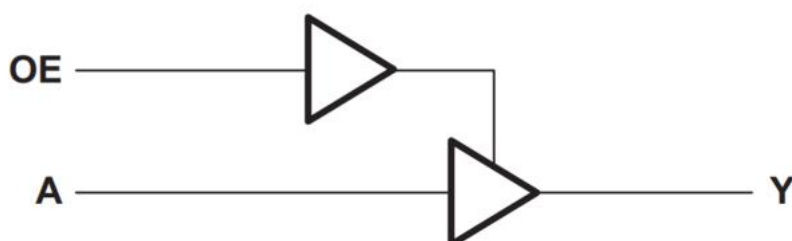
## Order information

Mode	Package	Ordering Number	Packing Option
FLG74AUP1G126	SOT23-5	FLG74AUP1G126YSOT235G/TR	Tape and Reel,3000
	SC70	FLG74AUP1G126YSC70G/TR	Tape and Reel,3000

## Pin Configuration



## Simplified Schematic



## Pin Assignment

Pin Name	Pin No.	Pin Function
OE	1	Input
A	2	Input
GND	3	Ground
Y	4	Output
VCC	5	Power Pin

## Absolute Maximum Ratings (Note1)

- $V_{CC}$  ----- -0.5V to +4.6V
- $V_I$  ----- -0.5V to +4.6V
- $V_O$  (Voltage range applied to any output in the high-impedance or power-off state) ----- -0.3V to +4.6V
- $V_O$  (Voltage range applied to any output in the high or slow state) ----- -0.3V to  $V_{CC}+0.3V$
- Input clamp current ----- -50mA
- Output clamp current ----- -50mA
- Continuous output current -----  $\pm 20mA$
- Storage Temperature -----  $-65^{\circ}C$  to  $150^{\circ}C$

## Recommended Operating Conditions

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply voltage	$V_{CC}$	Operating	0.8		3.6	V
Input voltage	$V_I$		0		3.6	V
Output voltage	$V_O$		0		$V_{CC}$	V
High- level input voltage	$V_{IH}$	$V_{CC} = 0.8V$	$V_{CC}$			V
		$V_{CC} = 1.1V$ to $1.95V$	$0.65 \times V_{CC}$			
		$V_{CC} = 2.3V$ to $2.7V$	1.6			
		$V_{CC} = 3V$ to $3.6V$	2			
Low- level input voltage	$V_{IL}$	$V_{CC} = 0.8V$			0	V
		$V_{CC} = 1.1V$ to $1.95V$			$0.35 \times V_{CC}$	
		$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 3V$ to $3.6V$			0.9	
High- level output current	$I_{OH}$	$V_{CC} = 0.8V$			-20	uA
		$V_{CC} = 1.1V$			-1.1	mA
		$V_{CC} = 1.4V$			-1.7	
		$V_{CC} = 1.65V$			-1.9	
		$V_{CC} = 2.3V$			-3.1	
		$V_{CC} = 3V$			-4	
Low- level output current	$I_{OL}$	$V_{CC} = 0.8V$			20	uA
		$V_{CC} = 1.1V$			1.1	mA
		$V_{CC} = 1.4V$			1.7	
		$V_{CC} = 1.65V$			1.9	
		$V_{CC} = 2.3V$			3.1	
		$V_{CC} = 3V$			4	
Input transition rise or fall rate	$\Delta T/\Delta V$	$V_{CC} = 0.8V$ to $3.6V$			200	ns/V
Operating temperature	$T_A$		-40		85	$^{\circ}C$

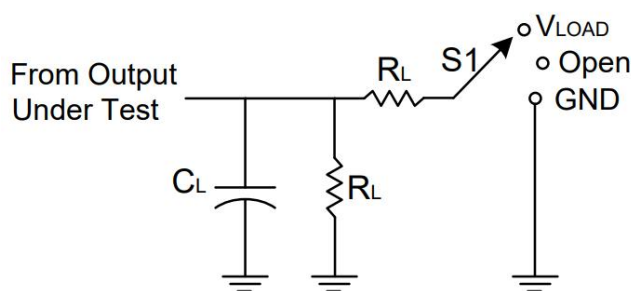
## Electrical Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
High- level output voltage	V <sub>OH</sub>	V <sub>CC</sub> = 0.8~3.6V, I <sub>OH</sub> = -20uA	V <sub>CC</sub> -0.1			V
		V <sub>CC</sub> = 1.1V, I <sub>OH</sub> = -1.1mA	0.75×V <sub>CC</sub>			
		V <sub>CC</sub> = 1.4V, I <sub>OH</sub> = -1.7mA	1.11			
		V <sub>CC</sub> = 1.65V, I <sub>OH</sub> = -1.9mA	1.32			
		V <sub>CC</sub> = 2.3V, I <sub>OH</sub> = -2.3mA	2.05			
		V <sub>CC</sub> = 2.3V, I <sub>OH</sub> = -3.1mA	1.9			
		V <sub>CC</sub> = 3V, I <sub>OH</sub> = -2.7mA	2.72			
		V <sub>CC</sub> = 3V, I <sub>OH</sub> = -4mA	2.6			
Low- level output voltage	V <sub>OL</sub>	V <sub>CC</sub> = 0.8~3.6V, I <sub>OL</sub> = 20uA			0.1	V
		V <sub>CC</sub> = 1.1V, I <sub>OL</sub> = 1.1mA			0.3×V <sub>CC</sub>	
		V <sub>CC</sub> = 1.4V, I <sub>OL</sub> = 1.7mA			0.31	
		V <sub>CC</sub> = 1.65V, I <sub>OL</sub> = 1.9mA			0.31	
		V <sub>CC</sub> = 2.3V, I <sub>OL</sub> = 2.3mA			0.31	
		V <sub>CC</sub> = 2.3V, I <sub>OL</sub> = 3.1mA			0.44	
		V <sub>CC</sub> = 3V, I <sub>OL</sub> = 2.7mA			0.31	
		V <sub>CC</sub> = 3V, I <sub>OL</sub> = 4mA			0.44	
Input leakage current	I <sub>I</sub>	V <sub>IN</sub> = 3.6V or GND, V <sub>CC</sub> = 0~3.6V			0.1	uA
Power off leakage current	I <sub>OFF</sub>	V <sub>I</sub> or V <sub>O</sub> =0V to 3.6V, V <sub>CC</sub> =0V			0.2	uA
Supply current	I <sub>CC</sub>	V <sub>I</sub> = GND or (V <sub>CC</sub> to 3.6V), I <sub>OUT</sub> =0, V <sub>CC</sub> =0.8~3.6V			0.5	uA
Additional supply current per input pin	ΔI <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> -0.6V, I <sub>OUT</sub> =0			40	uA

## Switching Characteristics

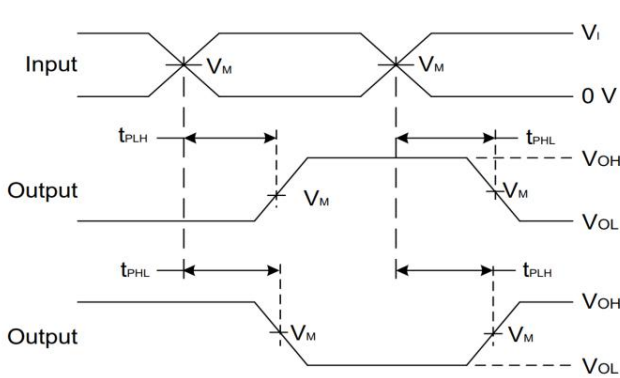
Parameter	From Input	To Output	Test Conditions	Min.	Typ.	Max.	Unit
T <sub>PD</sub>	A	Y	V <sub>CC</sub> = 0.8V		22.5		ns
			V <sub>CC</sub> = 1.2V±0.1V	5.8	9.3	15.1	
			V <sub>CC</sub> = 1.5V±0.1V	4.4	6.6	10.2	
			V <sub>CC</sub> = 1.8V±0.15V	3.5	5.3	8.3	
			V <sub>CC</sub> = 2.5V±0.2V	2.7	3.9	5.8	
			V <sub>CC</sub> = 3.3V±0.3V	2.4	3.2	4.7	
T <sub>en</sub>	OE	Y	V <sub>CC</sub> = 0.8V		25.2		ns
			V <sub>CC</sub> = 1.2V±0.1V	7	11.3	18.1	
			V <sub>CC</sub> = 1.5V±0.1V	5.5	8.1	12.2	
			V <sub>CC</sub> = 1.8V±0.15V	4.3	6.5	10.1	
			V <sub>CC</sub> = 2.5V±0.2V	3.4	4.8	7.1	
			V <sub>CC</sub> = 3.3V±0.3V	2.9	4.1	5.9	
T <sub>dis</sub>	OE	Y	V <sub>CC</sub> = 0.8V		14		ns
			V <sub>CC</sub> = 1.2V±0.1V	3.7	5.8	8.2	
			V <sub>CC</sub> = 1.5V±0.1V	5.5	3.9	5.9	
			V <sub>CC</sub> = 1.8V±0.15V	3.3	4.5	6.6	
			V <sub>CC</sub> = 2.5V±0.2V	2.3	3.2	4.3	
			V <sub>CC</sub> = 3.3V±0.3V	2.4	4.8	6.2	

## Parameter Measurement Information

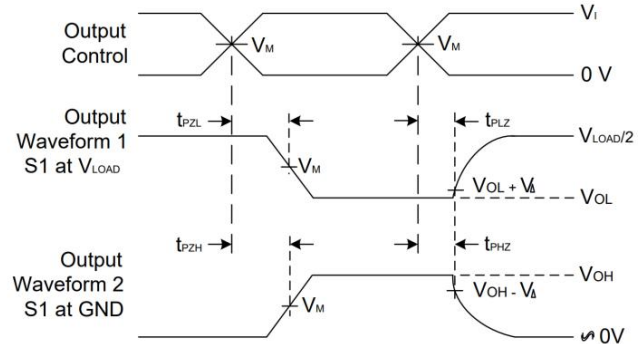


TEST	S1	R <sub>L</sub>
t <sub>PLH</sub> /t <sub>PHL</sub>	Open	1MΩ
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>	5KΩ
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND	5KΩ

$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	$C_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$				
0.8V	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.1V
$1.2V \pm 0.1V$	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.1V
$1.5V \pm 0.1V$	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.1V
$1.8V \pm 0.15V$	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.15V
$3.3V \pm 0.3V$	$V_{CC}$	$\cong 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	0.3V



Voltage Waveform Propagation Delay Times  
Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times  
Low- and High-Level Enabling

- Notes:
- A.  $C_L$  includes probe and jig capacitance
  - B. All pulses and supplied at pulse repetition rate  $\cong 10MHz$
  - C. The Inputs are measured separately one transition per measurement
  - D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$
  - E.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$
  - F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$

## IC Operation Information

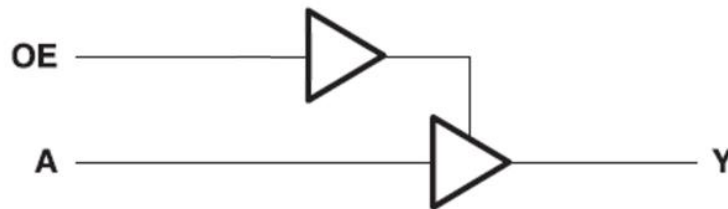
### Basic Operation

The AUP family is the solution to the industry's low-power needs in battery-powered portable applications. This family of devices is specified for low static and dynamic power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity.

This device contains one buffer gate device with output enable control and performs the Boolean function  $Y = A$ . This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device, which prevents damage to the device.

To assure the high-impedance state during power up or power down, OE must be tied to GND through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

### Function Block Diagram



### Feature Description

- Wide operating  $V_{CC}$  range of 0.8V to 3.6V.
- 3.6-V I/O tolerant to support down translation.
- Input hysteresis allows slow input transition and better switching noise immunity at the input.
- Ioff feature allows voltages on the inputs and outputs when  $V_{CC}$  is 0 V.
- Low noise due to slower edge rates.

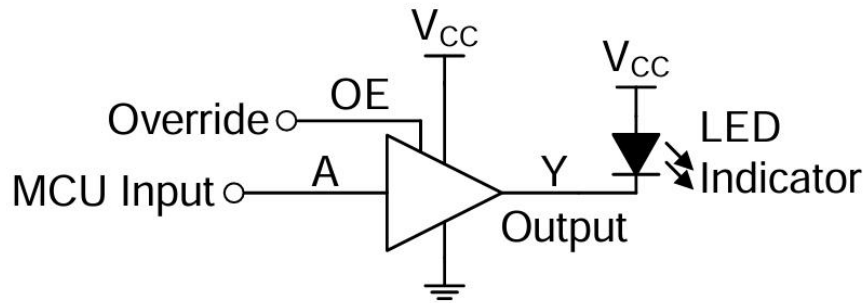
### Device Functional Table

INPUTS		OUTPUT
OE	A	Y
H	H	H
H	L	L
L	X	Z

### IC Application Information

The FLG74AUP1G126 device is an output enabled CMOS buffer that can be used in LED indicator applications that require less than 4 mA. The device can produce up to 4 mA of drive current at 3.3 V. The inputs to the device are also overvoltage tolerant up to 3.6 V, allowing it to translate down to any valid  $V_{CC}$ .

## Typical Application



## Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive also creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

## Detailed Design Procedure

### 1. Recommended Input conditions:

- Rise time and fall time specs. See ( $\Delta t/\Delta V$ ) in the Recommended Operating Conditions table.
- Specified high and low levels. See ( $V_{IH}$  and  $V_{IL}$ ) in the Recommended Operating Conditions table.
- Inputs are overvoltage tolerant allowing them to go as high as ( $V_I$  max) in the Recommended Operating Conditions table at any valid  $V_{CC}$

### 2. Recommended output conditions:

- Load currents should not exceed ( $I_O$  max) per output and should not exceed total current (continuous current through  $V_{CC}$  or GND) for the part. These limits are located in the Absolute Maximum Ratings table.
- Outputs should not be pulled above  $V_{CC}$

## Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

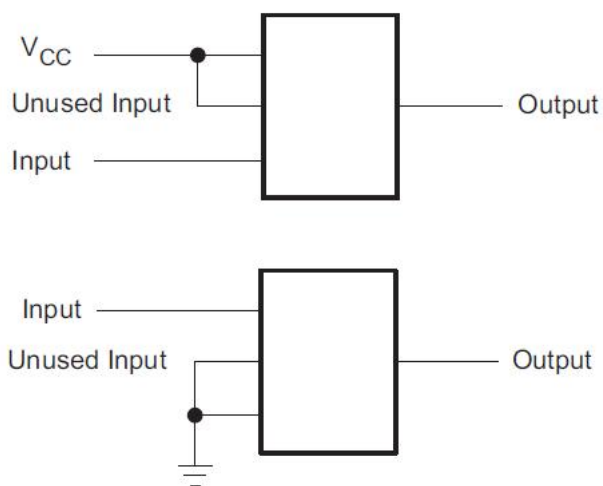
The VCC pin must have a good bypass capacitor to prevent power disturbance. It's recommended to use a 0.1- $\mu$ F capacitor for this device. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. Install the bypass capacitor as close to the power pin as possible for best results.

## Layout Considerations

When using multiple-bit logic devices, inputs should never float.

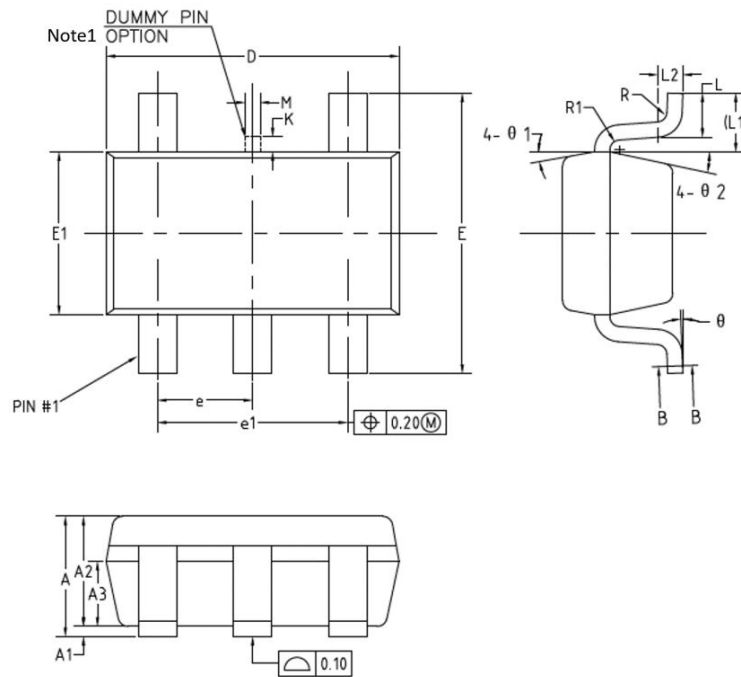
In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Below figure specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a

high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or VCC, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.



## Package Information

(1) Package Type: SOT23-5

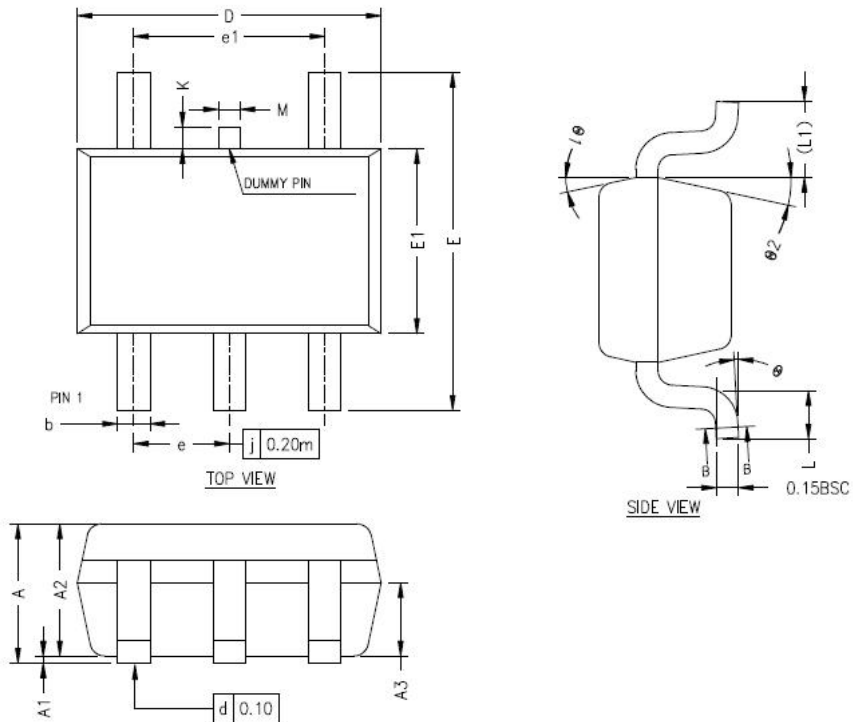


COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	—	—	1.25
A1	0	—	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
⚠ b	0.34	—	0.45
⚠ b1	0.34	0.38	0.41
⚠ c	0.12	—	0.20
⚠ c1	0.12	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
⚠ E1	1.526	1.626	1.700
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
⚠ K	0	—	0.20
L	0.30	0.40	0.60
L1	0.59REF		
L2	0.25BSC		
⚠ M	0.10	0.15	0.20
R	0.05	—	0.20
R1	0.05	—	0.20
θ	0°	—	8°
θ 1	8°	10°	12°
θ 2	10°	12°	14°

Notes: 1. Dummy pin may differ or may not be present.

(2) Package Type: SC70



COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.80	—	1.10
A1	0	—	0.10
A2	0.80	0.90	1.00
A3	0.40	0.50	0.60
b	0.17	—	0.30
b1	0.17	0.22	0.25
$\triangle_3$ c	0.12	—	0.20
$\triangle_3$ c1	0.12	0.15	0.16
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.21	1.26	1.31
e	0.60	0.65	0.70
e1	1.20	1.30	1.40
L	0.26	0.33	0.46
L1	0.52REF		
$\triangle_2$ M	0.10	0.15	0.20
$\triangle_2$ K	0	—	0.20
$\theta$	0°	—	8°
$\theta_1$	10°	12°	14°
$\theta_2$	10°	12°	14°

## Important Notice And Disclaimer

- We reserves the right to change the instruction manual without prior notice.
- Any semiconductor product has a certain possibility of failure or malfunction under specific conditions. The buyer is responsible for complying with safety standards and taking safety measures when using our products for system design and overall manufacturing to avoid potential failure risks that may cause personal injury or property damage.
- The improvement of product quality is endless, our company will be dedicated to provide customers with better products.